MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet





- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Extremely small surface mounting type.(DFN0603)
- Low IR.
- High reliability.

APPLICATIONS

• Low current rectification



0201

MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
DC Reverse Voltage	VR	30	V
Mean Rectifying Current	Ю	100	mA
Peak Forward Surge Current	IFSM	2	Α

THERMAL CHARACTERISTICS

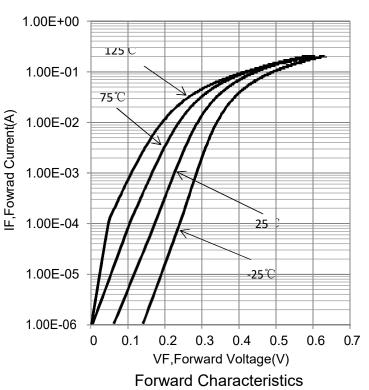
Parameter	Symbol	Limits	Unit
Total Device Dissipation,	PD		
FR-5 Board (Note 1) @ TA = 25°C		200	mW
Derate above 25°C		1.58	mW/ºC
Thermal Resistance,	RΘJA	500	°C/W
Junction-to-Ambient(Note 1)			
Junction Temperature	TJ	125	°C
Storage Temperature Range	Tstg	−40∼+150	°C
Operating Temperature Range	Тор	−40∼+125	°C

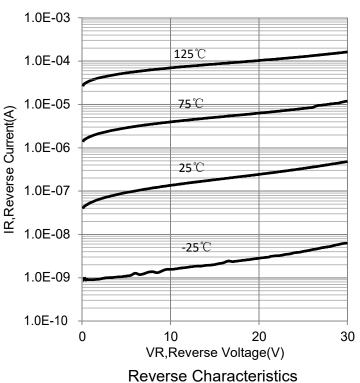
^{1.} $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

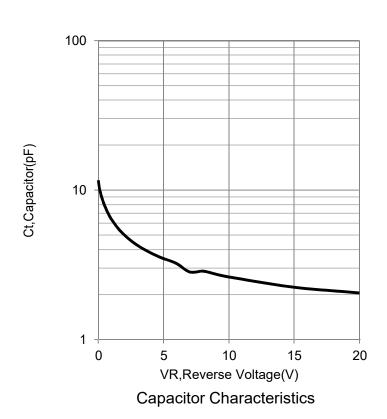
ELECTRICAL CHARACTERISTICS (Ta= 25°C)

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Reverse Voltage Leakage Current	IR				μA
(VR = 10Vdc)		-	-	0.35	
(VR = 30Vdc)		-	-	0.7	
Diode Capacitance	СТ				pF
(VR = 0V , f = 1.0 MHz)	СТ	-	8.2	-	
Forward Voltage	VF				V
(IF = 100 mAdc)		-	-	0.62	
(IF = 10 mAdc)		-	-	0.5	

ELECTRICAL CHARACTERISTICS CURVES

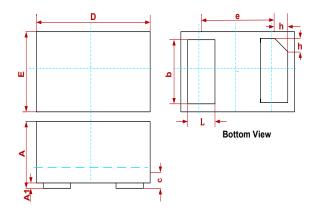






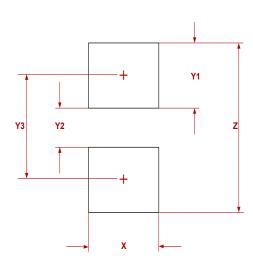


PACKAGE MECHANICAL DATA



	DIMENSIONS			
	MILLIMETERS			
SYM	MIN	NOM		MAX
Α	0.230			0.330
A1	0.000	0.020		0.050
b	0.215	0.245		0.275
С	0.120	0.150		0.180
D	0.550	0.600		0.650
е	0.355 BSC			
Е	0.250	0.300		0.350
L	0.160	0.190		0.220
h	0.079 BSC			

Suggested Pad Layout



SYM	DIMENS	IONS
STIVI	MILLIMETERS	INCHES
Х	0.30	0.012
Y1	0.25	0.010
Y2	0.15	0.006
Y3	0.40	0.016
Z	0.65	0.026

REEL SPECIFICATION

P/N	PKG	QTY
BAT30F4-MS	0201	10000



Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specificationsof any andall MSKSEMI Semiconductor products described orcontained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringementsof intellectual property rights or other rightsof third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.